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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
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10/664,379

09/17/2003

Darrin Benzer

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EXAMINER

NGUYEN, LONG T

ART UNIT

PAPER NUMBER

2816

DATE MAILED: 01/26/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

8

Office Action Summary	Application No.	Applicant(s)	
	10/664,379	BENZER ET AL.	
	Examiner	Art Unit	
	Long Nguyen	2816	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 10 November 2005.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 9-26 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 9-26 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 17 September 2003 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|---|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 11/10/05 has been entered.

Claim Rejections - 35 USC § 112

2. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

3. Claims 19-24 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

With respect to claims and 20, the recitation "eliminating static current drain" recited on the last line of these claims is indefinite because it is not clear the static current drain of which element.

Claims 21-24 are indefinite because they include the indefiniteness of claim 20.

Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

5. Claims 9-26 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hirano (USP 5,650,742) in view of Cress et al. (USP 6,483,386).

With respect to claims 9-15, 25 and 26, each of Figures 12 of the Hirano reference discloses a level shifter circuit, which meets a method of translating a voltage level of a single-ended input signal (I12) using at least one pass NMOS transistor device (either Qn1201 or Qn1204) including: outputting a first voltage level if the single-ended input signal is in a first state (i.e., if the first state of the input signal I12 is at logic Lo, the output O12 of the circuit is at logic Hi; and if the first state of the input signal I12 is at logic Hi, the output O12 of the circuit is at logic Lo); and outputting a second voltage level if the single ended input is in a second state (i.e., if the first state of the input signal I12 is at logic Hi, the output O12 of the circuit is at logic Lo; and if the first state of the input signal I12 is at logic Lo, the output O12 of the circuit is at logic Hi). The Hirano reference does not disclose that the at least one pass NMOS transistor device is a native NMOS transistor device having a threshold voltage less than 0V. However, the Cress et al. reference discloses (note M3 in Figure 5, lines 45-65 of Col. 2, lines 18-43 of Col. 3, and lines 4-31 of Col. 4 of Cress et al.) a pass transistor device (M3) is a native NMOS transistor device having a threshold voltage less than 0V (-200mV, see lines 34-36 of Col. 3 of Cress et al.) for the purpose of having an input signal fully passes through the pass NMOS transistor device because the use of a native NMOS as a pass transistor provides a signal with low signal distortion (see line 24-31 of Col. 4, Cress et al.). Therefore, it would have been obvious to one having skill in the art at the time the invention was made to modify the circuits in Figure 12 of the Hirano reference by specifically using the native NMOS pass transistor (M3) having a threshold voltage of less than 0V, as taught by the Cress et al. reference, for the NMOS

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pass transistor (Qn1201 and Qn1202) for the purpose of reducing noise and improving the performance of the circuitry since native NMOS pass transistor provides a signal with low distortion. Thus, this modification meets all the limitations of these claims including the limitation that the at least one native NMOS transistor device having a threshold voltage less than 0V (-200mV as discussed above). Note that the at least one pass transistor having its gate that is grounded (i.e., for NMOS Qn1201, the gate having a voltage swing between ground Vss and Hi power supply Vpp, so the gate of Qn1201 is grounded when output O12 having voltage level of Vss 0V; and similarly, for NMOS Qn1202, the gate having a voltage swing between ground Vss and Lo power supply Vcc, so the gate of Qn1204 is grounded when node N1203 having voltage level of Vss 0V).

With respect to claim 16, the above modification of the level shifter circuit as discussed above (with regard to claim 9) meets all the limitation of this claim, i.e., the modification circuit discloses a level shifter circuit, which meets a method of translating a voltage level of a single-ended input signal (I12) using at least one native NMOS transistor device having a threshold voltage less than 0V (-200mv, see rejection of claim 9) including: determining if the input signal (I12) is high (input signal I12 having logic Hi, transistor Qn1202 turns ON); outputting a low signal if the input signal is high (output signal O12 is a low signal if the input signal I12 is high); and outputting a high signal if the input signal is not high (Qn1202 is off and Qp1202 is ON).

With respect to claim 17, the above modification meets the limitation that determining if the input signal is high includes determining if the input signal (I12) is greater than a first voltage (the threshold voltage of the n-channel transistor Qn1202, i.e., the input signal I12 is considered

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to be Hi when the input signal I12 is greater than the threshold voltage of the enhancement n-channel transistor Qn1202).

With respect to claim 18, the above modification meets the limitation that determining if the input signal (I12) is not high includes determining if the input signal is less than a second voltage (the threshold voltage of the p-channel transistor Qp1202, i.e., the input signal I12 is considered to be Lo when the input signal I12 is less than the threshold voltage of the enhancement p-channel transistor Qp1202, so transistor Qp1202 is ON).

Insofar as understood in claim 19, the above modification meets the limitation that eliminating static current drain (the feedback transistor Qp1201 in the above modification). Note that the structure of the above modification is similar as applicant's invention so if the feedback transistor of applicant's invention capable of eliminating static current drain then the feedback of Qp1201 in this modification also capable of eliminating static current drain.

Insofar as understood in claims 20-24, the above modification (as discussed above with regard to claim 9) meets all the limitations of these claims, i.e., the level shifter circuit having a single-end input (I12), a first native NMOS transistor (the replacement of the Qn1201 and Qn1204 as discussed in claim 9) having threshold voltage of less than 0V (-200mV, see discussion in claim 9), a second transistor (Qn1202), and a level shifter transistor (Qp1202). Note that the method steps recited in this claim are also met including: determining if the input signal is greater than a threshold value of the second transistor (Qn1202 turns ON if input signal I12 is greater than threshold value of Qn1202, respectively); outputting a low signal if the input signal is greater than the threshold value (Qn1202 turns ON if input signal I12 is greater than threshold value of Qn1202, so output O12 is Lo and having a ground voltage level); outputting a Hi signal

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if the input signal is not greater than the threshold value (if input signal I12 is not greater than threshold value of Qn1202, then Qp1202 turns ON so output O12 is Hi and having a VDD level); and eliminating static current drain (by feed back transistor Qp1201); and wherein outputting a high signal comprising determining if the input signal is "greater" than a second threshold value (the threshold of Qp1202 because if the input I12 or I30 is greater than the threshold of Qp1202, then Qp1202 turns off; note that Qp1202 turns On when I12 is less than the threshold of Qp1202); and determining if the input signal is less than the threshold value but greater than the second threshold value (the output signal is not determined Hi or Lo). Note that the structure of this modification is similar as applicant's invention so if the feedback transistor of applicant's invention capable of eliminating static current drain then the feedback of Qp1201 in this modification also capable of eliminating static current drain.

Response to Arguments

6. Applicant's arguments filed on 11/10/05 have been considered but are moot in view of the new ground(s) of rejection as discussed above in the rejection.

Conclusion

7. Any inquiry concerning this communication or earlier communications from the examiner should be directly to Examiner Long Nguyen whose telephone number is (571) 272-1753. The Examiner can normally be reached on Monday to Thursday from 8:00am to 6:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tim Callahan, can be reached at (571) 272-1740. The fax number for this group is (571) 273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

January 23, 2006

A handwritten signature in cursive script, appearing to read 'Long Nguyen', with a long horizontal flourish extending to the right.

LONG NGUYEN
PRIMARY EXAMINER